Pin Diode Switch Element

Features
- Supports up to 20 W Power
- Low Insertion Loss: 0.2 dB up to 2.7 GHz
- High Isolation: 18 dB up to 2.7 GHz
- RoHS* Compliant

Description
A broadband medium power switch element in a 1.9 x 1.1 mm DFN package. This device is electrical series and thermal direct to ground (EST2G). This device is designed for wireless infrastructure applications and test instruments. It is also suited for other applications from 100 MHz up to 6 GHz.

Electrical Specifications: $T_C = +25\degree C$ (unless otherwise specified)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Test Conditions</th>
<th>Units</th>
<th>Min.</th>
<th>Typ.</th>
<th>Max.</th>
</tr>
</thead>
<tbody>
<tr>
<td>Breakdown Voltage ($V_{BR}$)</td>
<td>$I_R = 10 \mu A$</td>
<td>V</td>
<td>100</td>
<td>—</td>
<td>—</td>
</tr>
<tr>
<td>Lifetime ($t$)</td>
<td>$I_F = 10 \ mA, I_R = 6 \ mA, 10% / 90%$</td>
<td>ns</td>
<td>—</td>
<td>50</td>
<td>—</td>
</tr>
<tr>
<td>Series Resistance ($R_S$)</td>
<td>$I_F = 100 \ mA, 50 \ MHz$</td>
<td>Ω</td>
<td>—</td>
<td>1.2</td>
<td>—</td>
</tr>
<tr>
<td>Junction Capacitance ($C_J$)</td>
<td>$V_R = -10 \ V, 1 \ MHz$</td>
<td>pF</td>
<td>0.08</td>
<td>—</td>
<td>—</td>
</tr>
<tr>
<td>Insertion Loss ($I_I$)</td>
<td>$I_F = 50 \ mA, 2.3 - 2.7 \ GHz$</td>
<td>dB</td>
<td>—</td>
<td>0.2</td>
<td>0.3</td>
</tr>
<tr>
<td></td>
<td>$I_F = 50 \ mA, &lt;6 \ GHz$</td>
<td></td>
<td></td>
<td>0.3</td>
<td>—</td>
</tr>
<tr>
<td>Input Return Loss ($I_{IR}$)</td>
<td>$I_F = 50 \ mA, 2.3 - 2.7 \ GHz$</td>
<td>dB</td>
<td>23</td>
<td>27</td>
<td>—</td>
</tr>
<tr>
<td></td>
<td>$I_F = 50 \ mA, &lt;6 \ GHz$</td>
<td></td>
<td>18</td>
<td>22</td>
<td>—</td>
</tr>
<tr>
<td>Isolation ($I_{ISO}$)</td>
<td>$V_R = -10 \ mA, 2.3 - 2.7 \ GHz$</td>
<td>dB</td>
<td>15</td>
<td>18</td>
<td>—</td>
</tr>
<tr>
<td></td>
<td>$V_R = -10 \ mA, &lt;6 \ GHz$</td>
<td></td>
<td>10</td>
<td>12</td>
<td>—</td>
</tr>
</tbody>
</table>

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Absolute Maximum Ratings\(^1,2\)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Absolute Maximum</th>
</tr>
</thead>
<tbody>
<tr>
<td>Breakdown Voltage ((V_{BR}))</td>
<td>100 V</td>
</tr>
<tr>
<td>Forward Current ((I_F))</td>
<td>100 mA</td>
</tr>
<tr>
<td>Theta ((\theta_{JC}))</td>
<td>65°C/W</td>
</tr>
<tr>
<td>Junction Temperature ((T_J))</td>
<td>175°C</td>
</tr>
<tr>
<td>Storage Temperature ((T_{STG}))</td>
<td>-65°C to +150°C</td>
</tr>
<tr>
<td>Mounting Temperature ((T_{MTG}))</td>
<td>+260°C per JEDEC STD-J-20C</td>
</tr>
</tbody>
</table>

1. Exceeding any one or combination of these limits may cause permanent damage to this device.
2. MACOM does not recommend sustained operation near these survivability limits.

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these Class 0 (HBM) devices.

Typical Performance Curves: \(T_A = 25°C, Z_O = 50 \, \Omega\), Small Signal

### Insertion Loss

- **Freq. GHz**: 0, 1, 2, 3, 4, 5, 6
- **Insertion Loss, dB**:
  - 10 mA
  - 20 mA
  - 40 mA
  - 100 mA

### Isolation

- **Freq. GHz**: 0, 1, 2, 3, 4, 5, 6
- **Isolation, dB**:
  - 50 V
  - 20 V
  - 10 V

### Input Return Loss

- **Freq. GHz**: 0, 1, 2, 3, 4, 5, 6
- **Input Return Loss, dB**:
  - 10 mA
  - 20 mA
  - 40 mA
  - 100 mA

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For further information and support please visit:
[https://www.macom.com/support](https://www.macom.com/support)
Printed Circuit Board Layout (Soldering Footprint)\textsuperscript{3,4,5,6,7}

3. Unless otherwise specified: Tolerance ±0.10 mm
4. If possible, use copper filled vias underneath pin 3 for better thermals; otherwise, use vias that are plated through, filled and plated over.
5. Solder mask should provide a 60 µm clearance between copper pad and soldermask. Rounded package pads should have matching rounded solder mask openings.
6. Use circles or squares for thermal land stencil such that there is only 50% to 80% solder paste coverage
7. 20 mils Rogers RO4350B with 1 oz. copper clad and 10 mil diameter plated thru vias on 20 mil centers underneath package.
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Package Outline

Dimensions in inches [mm]

Notes:
1. LEAD FRAME MATERIAL: 8 ML COPPER.
2. BOTH TERMINAL SPACING: Ni: 0.54 ± 0.04 mm
3. DIMENSIONS IN PARENTHESES ARE IN MM.

Visit www.macom.com for additional data sheets and product information.

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